

# 74AUP2G132

## Low-power dual 2-input NAND Schmitt trigger

Rev. 7 — 8 February 2013

Product data sheet

### 1. General description

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The 74AUP2G132 provides the dual 2-input NAND Schmitt trigger function which accepts standard input signals. They can transform slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage  $V_H$ .

### 2. Features and benefits

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- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot  $< 10\%$  of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$

### 3. Applications

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- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



## 4. Ordering information

Table 1. Ordering information

| Type number  | Package           |        |                                                                                             |          |
|--------------|-------------------|--------|---------------------------------------------------------------------------------------------|----------|
|              | Temperature range | Name   | Description                                                                                 | Version  |
| 74AUP2G132DC | –40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                  | SOT765-1 |
| 74AUP2G132GT | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 |
| 74AUP2G132GF | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm         | SOT1089  |
| 74AUP2G132GD | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm    | SOT996-2 |
| 74AUP2G132GM | –40 °C to +125 °C | XQFN8  | plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm   | SOT902-2 |
| 74AUP2G132GN | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm       | SOT1116  |
| 74AUP2G132GS | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm      | SOT1203  |

## 5. Marking

Table 2. Marking codes

| Type number  | Marking code <sup>[1]</sup> |
|--------------|-----------------------------|
| 74AUP2G132DC | aE2                         |
| 74AUP2G132GT | aE2                         |
| 74AUP2G132GF | aE                          |
| 74AUP2G132GD | aE2                         |
| 74AUP2G132GM | aE2                         |
| 74AUP2G132GN | aE                          |
| 74AUP2G132GS | aE                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 6. Functional diagram

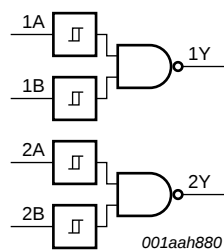


Fig 1. Logic symbol

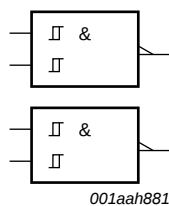


Fig 2. IEC logic symbol

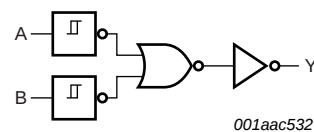
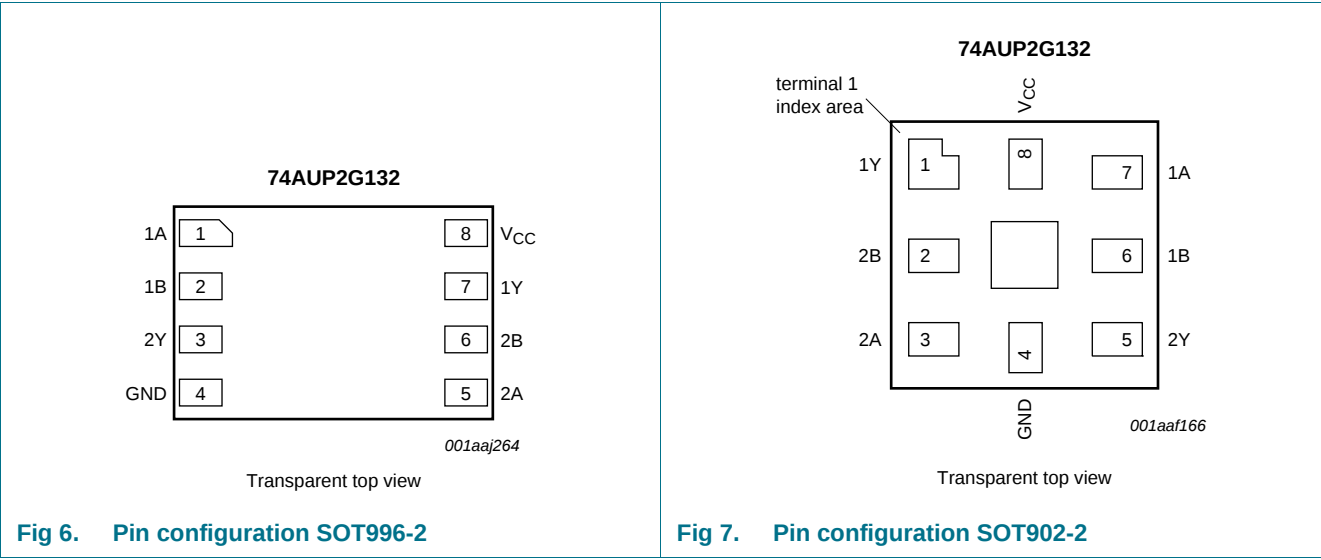
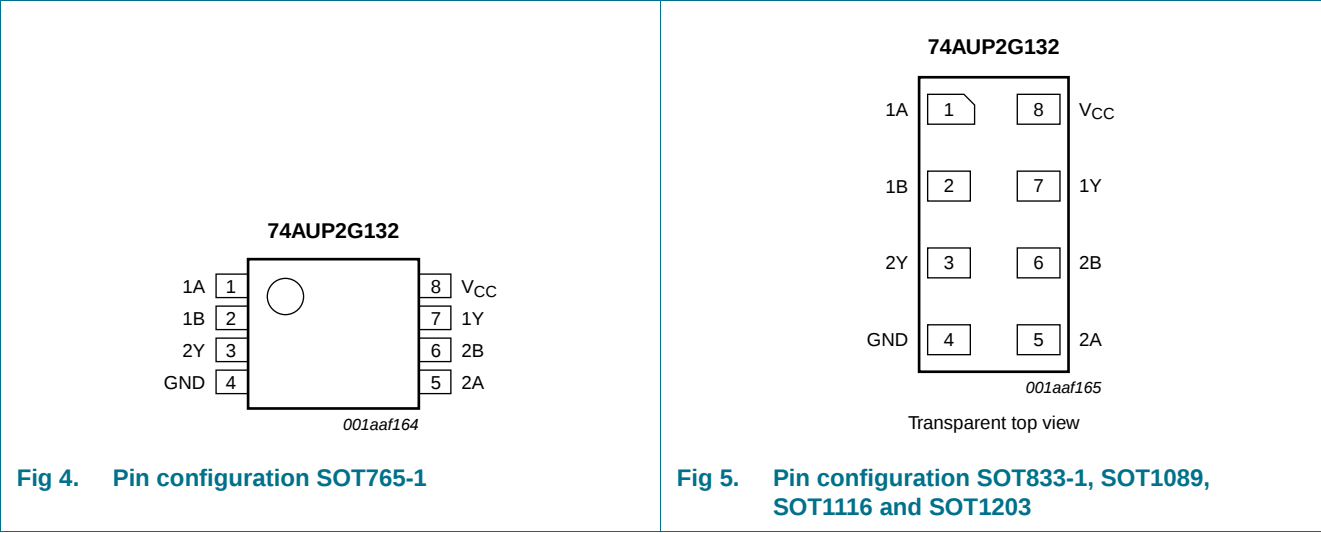


Fig 3. Logic diagram (one gate)

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol          | Pin                                                        |          | Description    |
|-----------------|------------------------------------------------------------|----------|----------------|
|                 | SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203 | SOT902-2 |                |
| 1A, 2A          | 1, 5                                                       | 7, 3     | data input     |
| 1B, 2B          | 2, 6                                                       | 6, 2     | data input     |
| GND             | 4                                                          | 4        | ground (0 V)   |
| 1Y, 2Y          | 7, 3                                                       | 1, 5     | data output    |
| V <sub>CC</sub> | 8                                                          | 8        | supply voltage |

## 8. Functional description

Table 4. Function table<sup>[1]</sup>

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | L  | H      |
| L     | H  | H      |
| H     | L  | H      |
| H     | H  | L      |

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                      | Min                 | Max  | Unit |
|-----------|-------------------------|---------------------------------|---------------------|------|------|
| $V_{CC}$  | supply voltage          |                                 | -0.5                | +4.6 | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                     | -50                 | -    | mA   |
| $V_I$     | input voltage           |                                 | <sup>[1]</sup> -0.5 | +4.6 | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                     | -50                 | -    | mA   |
| $V_O$     | output voltage          | Active mode and Power-down mode | <sup>[1]</sup> -0.5 | +4.6 | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$         | -                   | ±20  | mA   |
| $I_{CC}$  | supply current          |                                 | -                   | 50   | mA   |
| $I_{GND}$ | ground current          |                                 | -50                 | -    | mA   |
| $T_{stg}$ | storage temperature     |                                 | -65                 | +150 | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C   | <sup>[2]</sup> -    | 250  | mW   |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of  $P_{tot}$  derates linearly with 8.0 mW/K.  
For XSON8 and XQFN8 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 10. Recommended operating conditions

Table 6. Operating conditions

| Symbol    | Parameter           | Conditions                      | Min | Max      | Unit |
|-----------|---------------------|---------------------------------|-----|----------|------|
| $V_{CC}$  | supply voltage      |                                 | 0.8 | 3.6      | V    |
| $V_I$     | input voltage       |                                 | 0   | 3.6      | V    |
| $V_O$     | output voltage      | Active mode                     | 0   | $V_{CC}$ | V    |
|           |                     | Power-down mode; $V_{CC} = 0$ V | 0   | 3.6      | V    |
| $T_{amb}$ | ambient temperature |                                 | -40 | +125     | °C   |

## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                    | Parameter                            | Conditions                                                                                       | Min                    | Typ | Max                   | Unit |
|-------------------------------------------|--------------------------------------|--------------------------------------------------------------------------------------------------|------------------------|-----|-----------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b>            |                                      |                                                                                                  |                        |     |                       |      |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                        | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                | 0.75 × V <sub>CC</sub> | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                | 1.11                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                               | 1.32                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                | 2.05                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                | 1.9                    | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                | 2.72                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                | 2.6                    | -   | -                     | V    |
| V <sub>OL</sub>                           | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                         | -                      | -   | 0.1                   | V    |
|                                           |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                 | -                      | -   | 0.3 × V <sub>CC</sub> | V    |
|                                           |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                 | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.44                  | V    |
|                                           |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.31                  | V    |
|                                           |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.44                  | V    |
| I <sub>I</sub>                            | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                      | -   | ±0.1                  | µA   |
| I <sub>OFF</sub>                          | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                      | -   | ±0.2                  | µA   |
| ΔI <sub>OFF</sub>                         | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.2                  | µA   |
| I <sub>CC</sub>                           | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.5                   | µA   |
| ΔI <sub>CC</sub>                          | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V          | <a href="#">[1]</a> -  | -   | 40                    | µA   |
| C <sub>I</sub>                            | input capacitance                    | V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 0 V to 3.6 V                         | -                      | 1.1 | -                     | pF   |
| C <sub>O</sub>                            | output capacitance                   | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V                                                      | -                      | 1.7 | -                     | pF   |
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                                      |                                                                                                  |                        |     |                       |      |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                       |      |
|                                           |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                        | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                | 0.7 × V <sub>CC</sub>  | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                | 1.03                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                               | 1.30                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                | 1.97                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                | 1.85                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                | 2.67                   | -   | -                     | V    |
|                                           |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                | 2.55                   | -   | -                     | V    |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                            | Conditions                                                                                       | Min                    | Typ | Max                    | Unit |
|--------------------------------------------|--------------------------------------|--------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                         | -                      | -   | 0.1                    | V    |
|                                            |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                 | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                            |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                 | -                      | -   | 0.37                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                | -                      | -   | 0.35                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.33                   | V    |
|                                            |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.45                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.33                   | V    |
|                                            |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.45                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                      | -   | ±0.5                   | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                      | -   | ±0.5                   | µA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.6                   | µA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.9                    | µA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V          | <a href="#">[1]</a> -  | -   | 50                     | µA   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |                                                                                                  |                        |     |                        |      |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                        | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                | 0.93                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                               | 1.17                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                | 1.77                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                | 1.67                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                | 2.40                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                              |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                         | -                      | -   | 0.11                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                 | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                                            |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                 | -                      | -   | 0.41                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                | -                      | -   | 0.39                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                 | -                      | -   | 0.50                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                 | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                      | -   | ±0.75                  | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                      | -   | ±0.75                  | µA   |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                            | Conditions                                                                                         | Min   | Typ | Max        | Unit          |
|------------------|--------------------------------------|----------------------------------------------------------------------------------------------------|-------|-----|------------|---------------|
| $\Delta I_{OFF}$ | additional power-off leakage current | $V_I$ or $V_O = 0\text{ V}$ to $3.6\text{ V}$ ;<br>$V_{CC} = 0\text{ V}$ to $0.2\text{ V}$         | -     | -   | $\pm 0.75$ | $\mu\text{A}$ |
| $I_{CC}$         | supply current                       | $V_I = \text{GND}$ or $V_{CC}$ ; $I_O = 0\text{ A}$ ;<br>$V_{CC} = 0.8\text{ V}$ to $3.6\text{ V}$ | -     | -   | 1.4        | $\mu\text{A}$ |
| $\Delta I_{CC}$  | additional supply current            | $V_I = V_{CC} - 0.6\text{ V}$ ; $I_O = 0\text{ A}$ ;<br>$V_{CC} = 3.3\text{ V}$                    | [1] - | -   | 75         | $\mu\text{A}$ |

[1] One input at  $V_{CC} - 0.6\text{ V}$ , other input at  $V_{CC}$  or GND.

## 12. Dynamic characteristics

**Table 8.** Dynamic characteristicsVoltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol | Parameter | Conditions | $T_{amb} = 25\text{ }^{\circ}\text{C}$ |         |     | $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ |                              |                               | Unit |
|--------|-----------|------------|----------------------------------------|---------|-----|---------------------------------------------------------------------------|------------------------------|-------------------------------|------|
|        |           |            | Min                                    | Typ [1] | Max | Min                                                                       | Max (85 $^{\circ}\text{C}$ ) | Max (125 $^{\circ}\text{C}$ ) |      |

 **$C_L = 5\text{ pF}$** 

|          |                   |                                                  |     |      |      |     |      |      |    |
|----------|-------------------|--------------------------------------------------|-----|------|------|-----|------|------|----|
| $t_{pd}$ | propagation delay | nA or nB to nY; see <a href="#">Figure 8</a> [2] |     |      |      |     |      |      |    |
|          |                   | $V_{CC} = 0.8\text{ V}$                          | -   | 22.5 | -    | -   | -    | -    | ns |
|          |                   | $V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$        | 2.6 | 6.3  | 13.4 | 2.4 | 15.1 | 16.6 | ns |
|          |                   | $V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$        | 2.2 | 4.6  | 8.2  | 1.9 | 9.7  | 10.7 | ns |
|          |                   | $V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$      | 1.9 | 3.9  | 6.6  | 1.7 | 7.9  | 8.7  | ns |
|          |                   | $V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$        | 1.7 | 3.2  | 5.3  | 1.5 | 6.2  | 6.8  | ns |
|          |                   | $V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$        | 1.6 | 2.9  | 4.7  | 1.4 | 5.6  | 6.2  | ns |

 **$C_L = 10\text{ pF}$** 

|          |                   |                                                  |     |      |      |     |      |      |    |
|----------|-------------------|--------------------------------------------------|-----|------|------|-----|------|------|----|
| $t_{pd}$ | propagation delay | nA or nB to nY; see <a href="#">Figure 8</a> [2] |     |      |      |     |      |      |    |
|          |                   | $V_{CC} = 0.8\text{ V}$                          | -   | 26.1 | -    | -   | -    | -    | ns |
|          |                   | $V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$        | 3.0 | 7.2  | 15.4 | 2.7 | 17.3 | 19.0 | ns |
|          |                   | $V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$        | 2.5 | 5.2  | 9.3  | 2.2 | 11.0 | 12.1 | ns |
|          |                   | $V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$      | 2.3 | 4.5  | 7.5  | 2.0 | 9.0  | 9.9  | ns |
|          |                   | $V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$        | 2.1 | 3.8  | 6.1  | 1.8 | 7.2  | 7.9  | ns |
|          |                   | $V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$        | 2.0 | 3.5  | 5.5  | 1.8 | 6.5  | 7.2  | ns |

 **$C_L = 15\text{ pF}$** 

|          |                   |                                                  |     |      |      |     |      |      |    |
|----------|-------------------|--------------------------------------------------|-----|------|------|-----|------|------|----|
| $t_{pd}$ | propagation delay | nA or nB to nY; see <a href="#">Figure 8</a> [2] |     |      |      |     |      |      |    |
|          |                   | $V_{CC} = 0.8\text{ V}$                          | -   | 29.6 | -    | -   | -    | -    | ns |
|          |                   | $V_{CC} = 1.1\text{ V}$ to $1.3\text{ V}$        | 3.3 | 8.0  | 17.2 | 3.0 | 19.4 | 21.3 | ns |
|          |                   | $V_{CC} = 1.4\text{ V}$ to $1.6\text{ V}$        | 2.8 | 5.8  | 10.4 | 2.5 | 12.3 | 13.5 | ns |
|          |                   | $V_{CC} = 1.65\text{ V}$ to $1.95\text{ V}$      | 2.6 | 5.0  | 8.3  | 2.3 | 10.0 | 11.0 | ns |
|          |                   | $V_{CC} = 2.3\text{ V}$ to $2.7\text{ V}$        | 2.3 | 4.2  | 6.7  | 2.1 | 7.9  | 8.7  | ns |
|          |                   | $V_{CC} = 3.0\text{ V}$ to $3.6\text{ V}$        | 2.2 | 3.9  | 6.1  | 2.0 | 7.3  | 8.0  | ns |

**Table 8. Dynamic characteristics ...continued**

Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol                                        | Parameter                     | Conditions                                                                     | T <sub>amb</sub> = 25 °C |                    |      | T <sub>amb</sub> = –40 °C to +125 °C |             |              | Unit |
|-----------------------------------------------|-------------------------------|--------------------------------------------------------------------------------|--------------------------|--------------------|------|--------------------------------------|-------------|--------------|------|
|                                               |                               |                                                                                | Min                      | Typ <sup>[1]</sup> | Max  | Min                                  | Max (85 °C) | Max (125 °C) |      |
| C <sub>L</sub> = 30 pF                        |                               |                                                                                |                          |                    |      |                                      |             |              |      |
| t <sub>pd</sub>                               | propagation delay             | nA or nB to nY; see <a href="#">Figure 8</a> <sup>[2]</sup>                    |                          |                    |      |                                      |             |              |      |
|                                               |                               | V <sub>CC</sub> = 0.8 V                                                        | -                        | 39.9               | -    | -                                    | -           | -            | ns   |
|                                               |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                               | 4.3                      | 10.2               | 22.6 | 3.8                                  | 25.4        | 27.9         | ns   |
|                                               |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                               | 3.6                      | 7.3                | 13.3 | 3.2                                  | 15.8        | 17.4         | ns   |
|                                               |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                             | 3.2                      | 6.3                | 10.6 | 2.9                                  | 12.8        | 14.1         | ns   |
|                                               |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                               | 3.0                      | 5.3                | 8.5  | 2.7                                  | 10.1        | 11.1         | ns   |
|                                               |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                               | 2.8                      | 5.0                | 7.8  | 2.7                                  | 9.2         | 10.1         | ns   |
| C <sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF |                               |                                                                                |                          |                    |      |                                      |             |              |      |
| C <sub>PD</sub>                               | power dissipation capacitance | f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[3]</sup> |                          |                    |      |                                      |             |              |      |
|                                               |                               | V <sub>CC</sub> = 0.8 V                                                        | -                        | 2.6                | -    | -                                    | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                               | -                        | 2.9                | -    | -                                    | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                               | -                        | 3.0                | -    | -                                    | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                             | -                        | 3.2                | -    | -                                    | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                               | -                        | 3.8                | -    | -                                    | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                               | -                        | 4.4                | -    | -                                    | -           | -            | pF   |

[1] All typical values are measured at nominal V<sub>CC</sub>.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

13. Waveforms

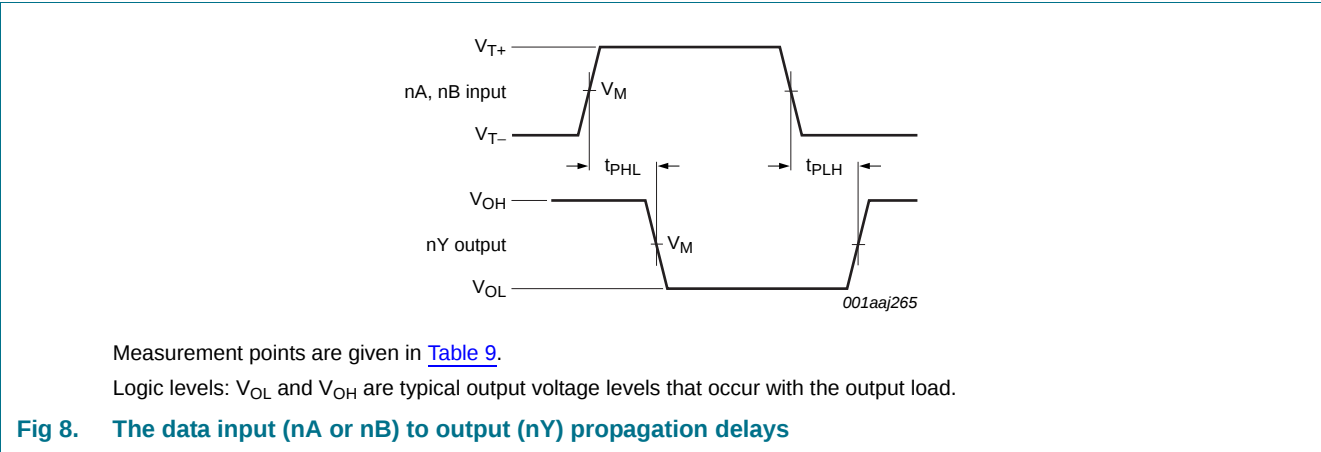


Table 9. Measurement points

| Supply voltage | Output              | Input               |          |                       |
|----------------|---------------------|---------------------|----------|-----------------------|
| $V_{CC}$       | $V_M$               | $V_M$               | $V_I$    | $t_r = t_f$           |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{CC}$ | $\leq 3.0 \text{ ns}$ |

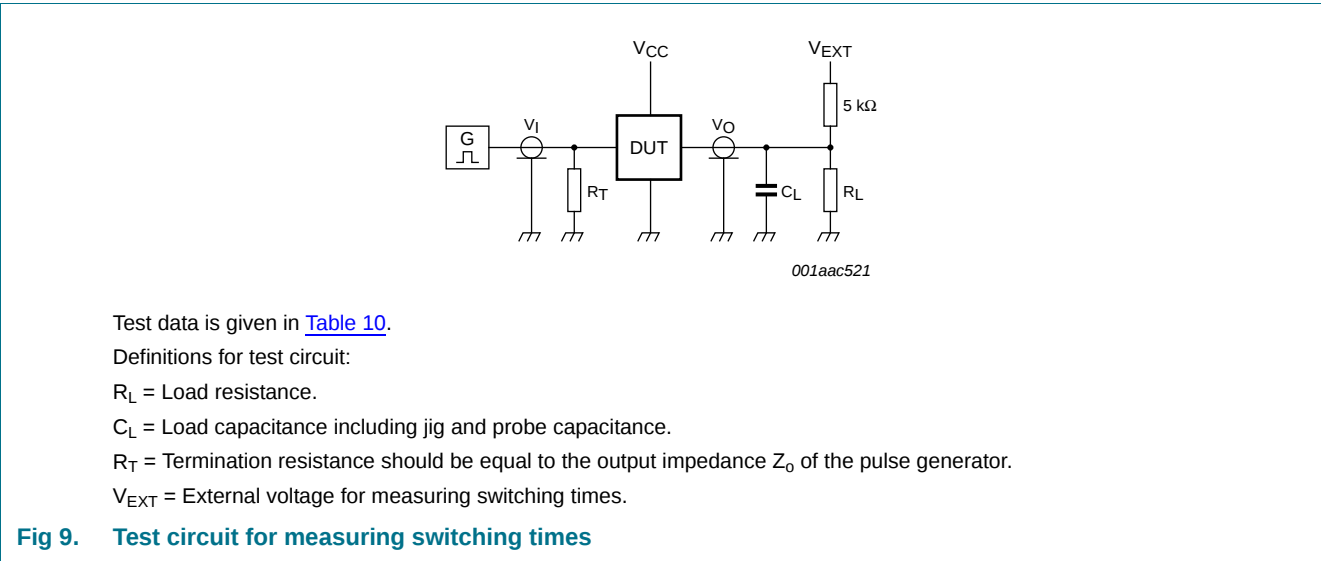


Table 10. Test data

| Supply voltage | Load                         |                      | $V_{EXT}$          |                    |                    |
|----------------|------------------------------|----------------------|--------------------|--------------------|--------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ <sup>[1]</sup> | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ         | open               | GND                | $2 \times V_{CC}$  |

[1]  $R_L = 5 \text{ k}\Omega$  when measuring enable and disable times.  $R_L = 1 \text{ M}\Omega$  when measuring propagation delays, setup and hold times and pulse width.

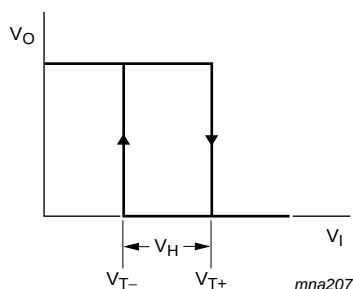
## 14. Transfer characteristics

**Table 11. Transfer characteristics**

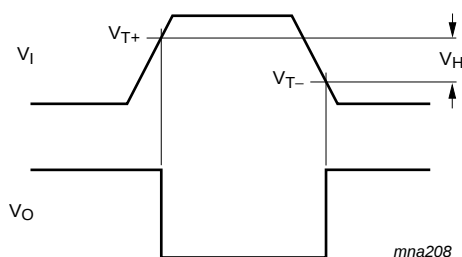
Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol   | Parameter                                                                                                                                                     | Conditions                                                  | $T_{amb} = 25\text{ °C}$ |     |      | $T_{amb} = -40\text{ °C to }+125\text{ °C}$ |             |              | Unit |
|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------|--------------------------|-----|------|---------------------------------------------|-------------|--------------|------|
|          |                                                                                                                                                               |                                                             | Min                      | Typ | Max  | Min                                         | Max (85 °C) | Max (125 °C) |      |
| $V_{T+}$ | positive-going threshold voltage                                                                                                                              | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a> |                          |     |      |                                             |             |              |      |
|          |                                                                                                                                                               | $V_{CC} = 0.8\text{ V}$                                     | 0.30                     | -   | 0.60 | 0.30                                        | 0.60        | 0.62         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.1\text{ V}$                                     | 0.53                     | -   | 0.90 | 0.53                                        | 0.90        | 0.92         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.4\text{ V}$                                     | 0.74                     | -   | 1.11 | 0.74                                        | 1.11        | 1.13         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.65\text{ V}$                                    | 0.91                     | -   | 1.29 | 0.91                                        | 1.29        | 1.31         | V    |
|          |                                                                                                                                                               | $V_{CC} = 2.3\text{ V}$                                     | 1.37                     | -   | 1.77 | 1.37                                        | 1.77        | 1.80         | V    |
|          |                                                                                                                                                               | $V_{CC} = 3.0\text{ V}$                                     | 1.88                     | -   | 2.29 | 1.88                                        | 2.29        | 2.32         | V    |
| $V_{T-}$ | negative-going threshold voltage                                                                                                                              | see <a href="#">Figure 10</a> and <a href="#">Figure 11</a> |                          |     |      |                                             |             |              |      |
|          |                                                                                                                                                               | $V_{CC} = 0.8\text{ V}$                                     | 0.10                     | -   | 0.60 | 0.10                                        | 0.60        | 0.60         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.1\text{ V}$                                     | 0.26                     | -   | 0.65 | 0.26                                        | 0.65        | 0.65         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.4\text{ V}$                                     | 0.39                     | -   | 0.75 | 0.39                                        | 0.75        | 0.75         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.65\text{ V}$                                    | 0.47                     | -   | 0.84 | 0.47                                        | 0.84        | 0.84         | V    |
|          |                                                                                                                                                               | $V_{CC} = 2.3\text{ V}$                                     | 0.69                     | -   | 1.04 | 0.69                                        | 1.04        | 1.04         | V    |
|          |                                                                                                                                                               | $V_{CC} = 3.0\text{ V}$                                     | 0.88                     | -   | 1.24 | 0.88                                        | 1.24        | 1.24         | V    |
| $V_H$    | hysteresis voltage ( $V_{T+} - V_{T-}$ ); see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> , <a href="#">Figure 12</a> and <a href="#">Figure 13</a> |                                                             |                          |     |      |                                             |             |              |      |
|          |                                                                                                                                                               | $V_{CC} = 0.8\text{ V}$                                     | 0.07                     | -   | 0.50 | 0.07                                        | 0.50        | 0.50         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.1\text{ V}$                                     | 0.08                     | -   | 0.46 | 0.08                                        | 0.46        | 0.46         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.4\text{ V}$                                     | 0.18                     | -   | 0.56 | 0.18                                        | 0.56        | 0.56         | V    |
|          |                                                                                                                                                               | $V_{CC} = 1.65\text{ V}$                                    | 0.27                     | -   | 0.66 | 0.27                                        | 0.66        | 0.66         | V    |
|          |                                                                                                                                                               | $V_{CC} = 2.3\text{ V}$                                     | 0.53                     | -   | 0.92 | 0.53                                        | 0.92        | 0.92         | V    |
|          |                                                                                                                                                               | $V_{CC} = 3.0\text{ V}$                                     | 0.79                     | -   | 1.31 | 0.79                                        | 1.31        | 1.31         | V    |

## 15. Waveforms transfer characteristics

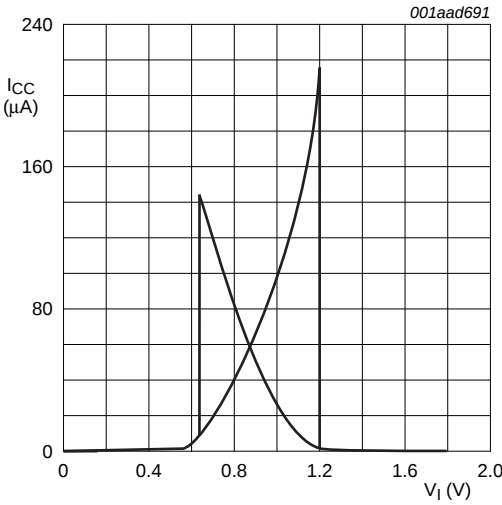


**Fig 10. Transfer characteristic**



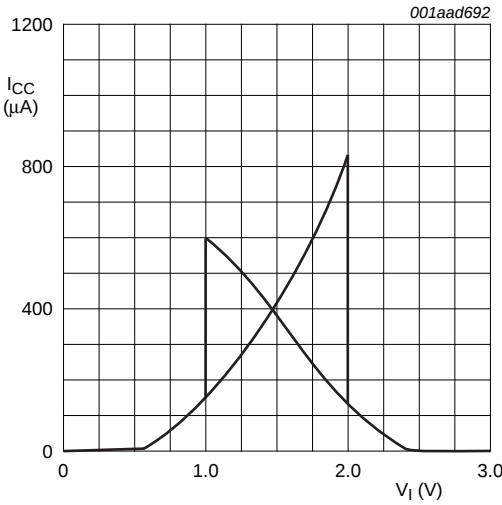
$V_{T+}$  and  $V_{T-}$  limits at 70 % and 20 %.

**Fig 11. Definition of  $V_{T+}$ ,  $V_{T-}$  and  $V_H$**



$V_{CC} = 3.0$  V.

Fig 12. Typical transfer characteristics;  $V_{CC} = 1.8$  V



$V_{CC} = 3.0$  V.

Fig 13. Typical transfer characteristics;  $V_{CC} = 3.0$  V

## 16. Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

$$P_{\text{add}} = f_i \times (t_r \times \Delta I_{\text{CC(AV)}} + t_f \times \Delta I_{\text{CC(AV)}}) \times V_{\text{CC}} \text{ where:}$$

$P_{\text{add}}$  = additional power dissipation ( $\mu\text{W}$ );

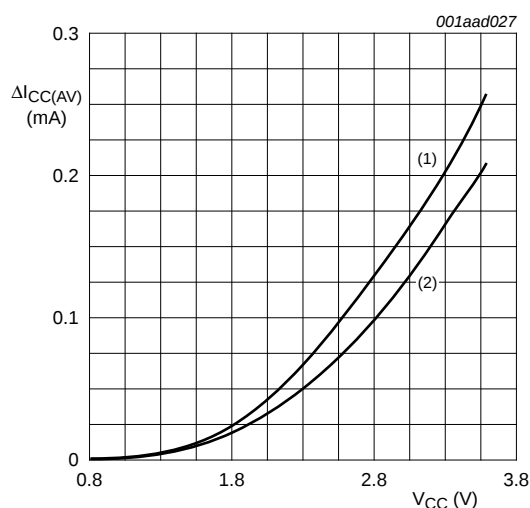
$f_i$  = input frequency (MHz);

$t_r$  = input rise time (ns); 10 % to 90 %;

$t_f$  = input fall time (ns); 90 % to 10 %;

$\Delta I_{\text{CC(AV)}}$  = average additional supply current ( $\mu\text{A}$ ).

Average  $\Delta I_{\text{CC(AV)}}$  differs with positive or negative input transitions, as shown in [Figure 14](#).



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of  $V_i$  between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

**Fig 14. Average  $I_{\text{CC}}$  as a function of  $V_{\text{CC}}$**

17. Package outline

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

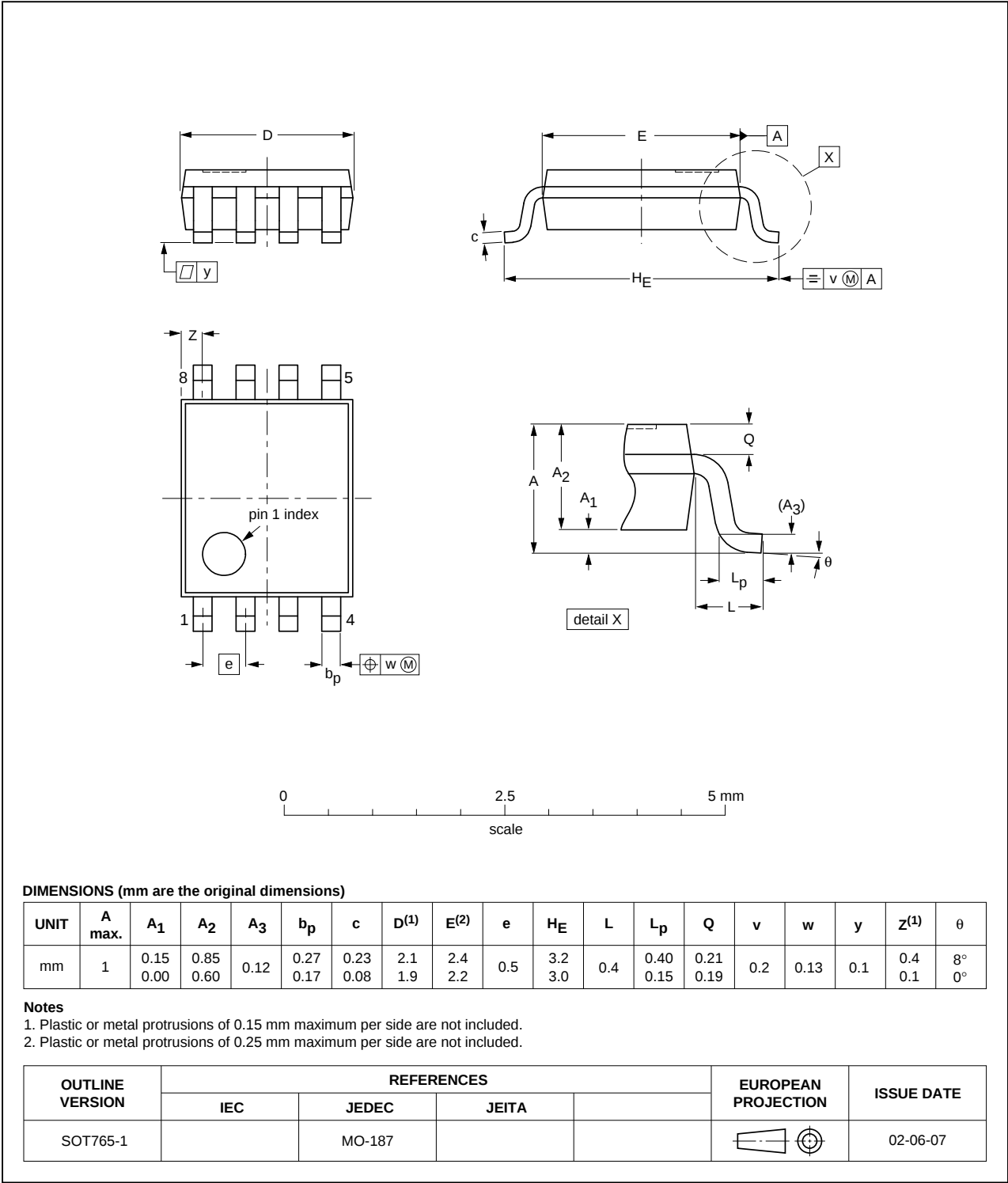


Fig 15. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

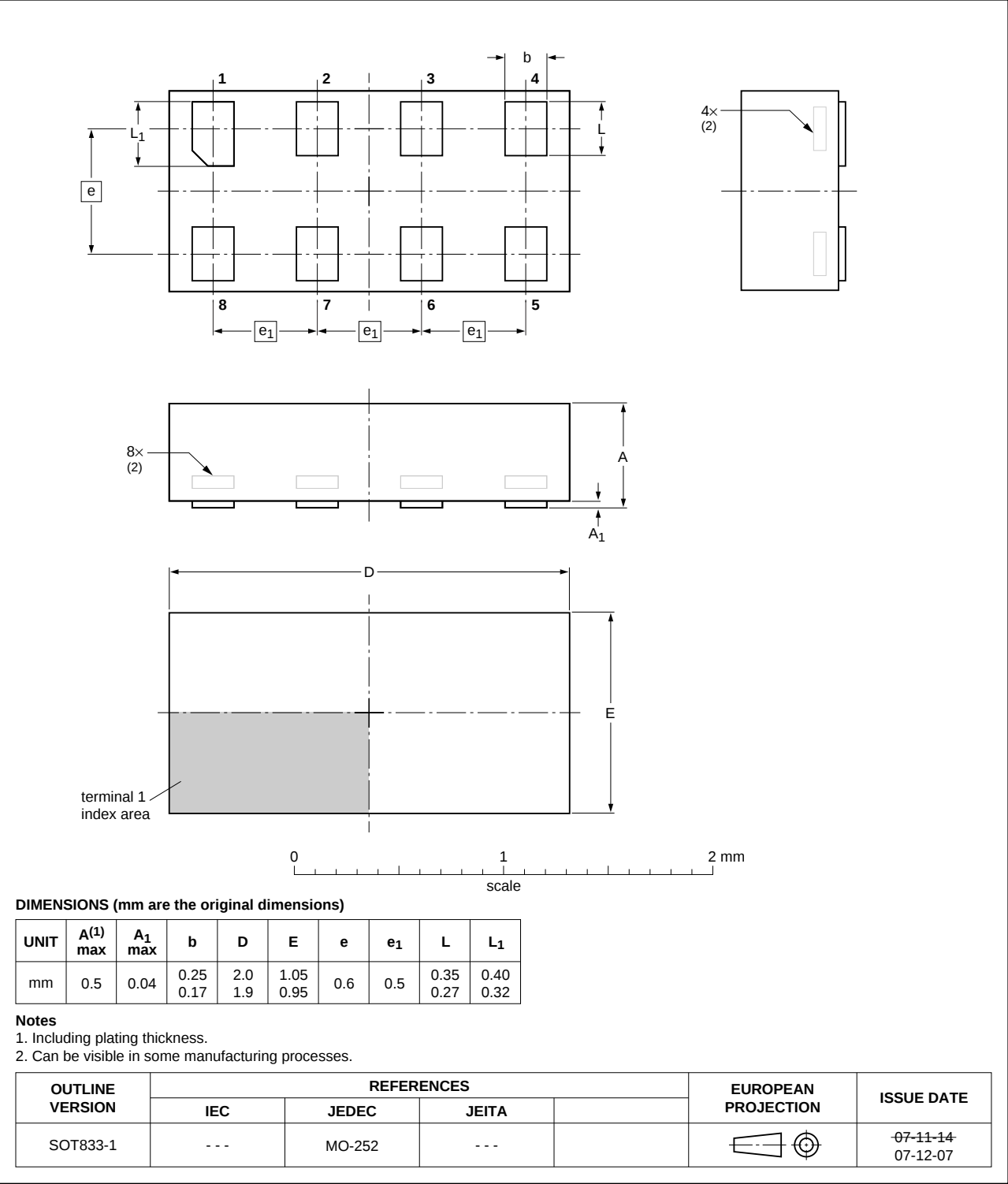


Fig 16. Package outline SOT833-1 (XSON8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1 x 0.5 mm

SOT1089

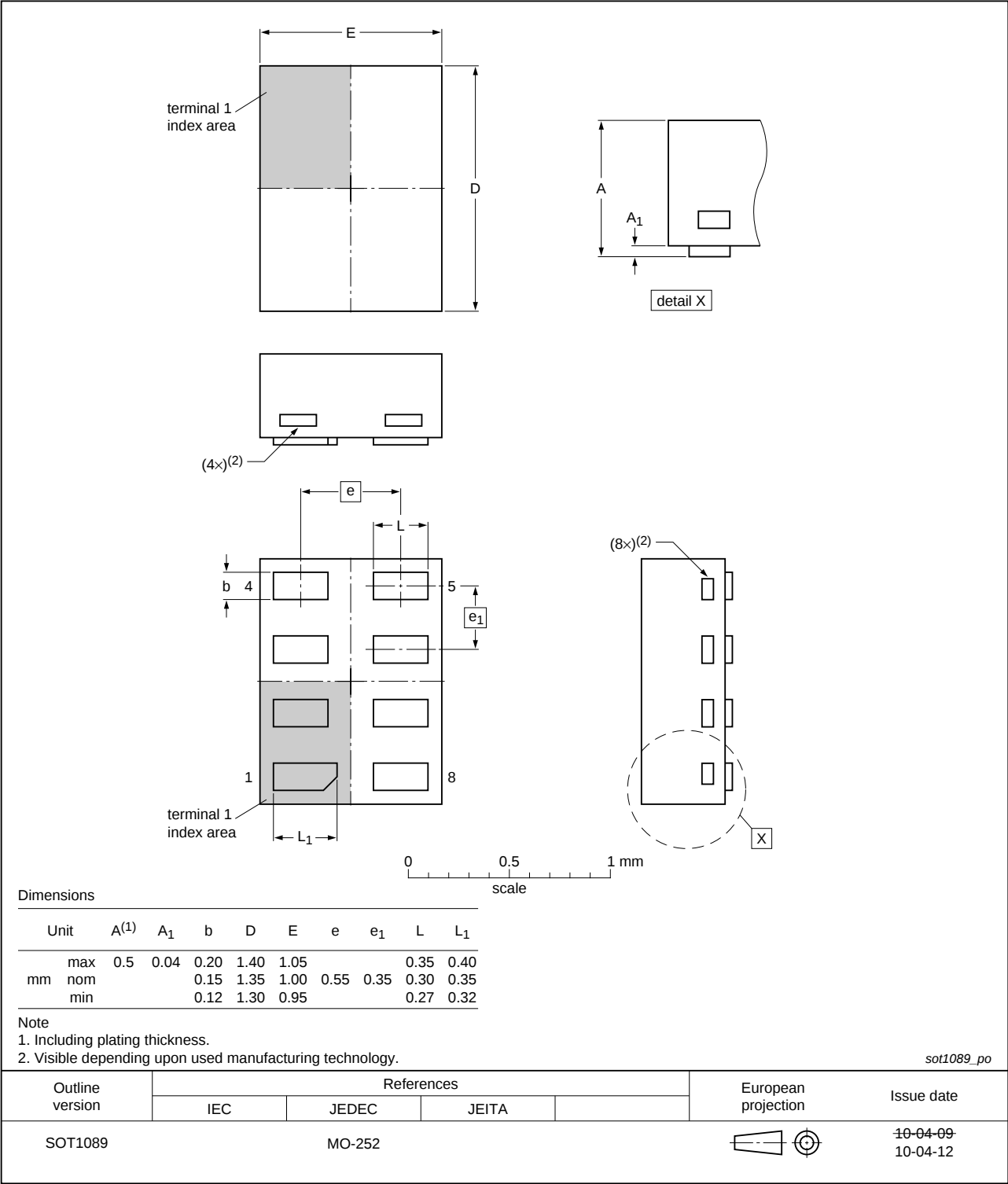


Fig 17. Package outline SOT1089 (XSON8)

XSON8: plastic extremely thin small outline package; no leads;  
8 terminals; body 3 x 2 x 0.5 mm

SOT996-2

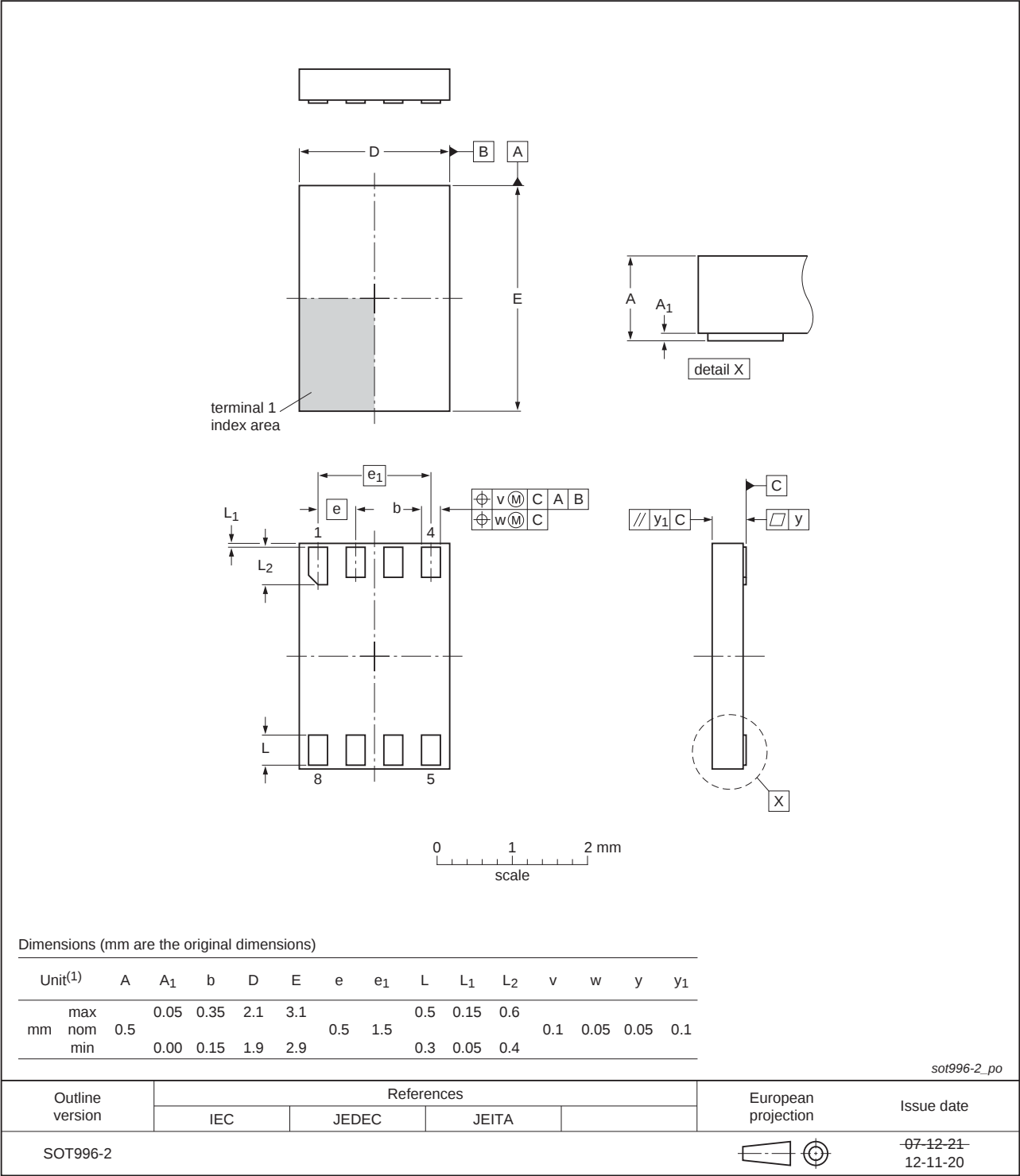


Fig 18. Package outline SOT996-2 (XSON8)

XQFN8: plastic, extremely thin quad flat package; no leads;  
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

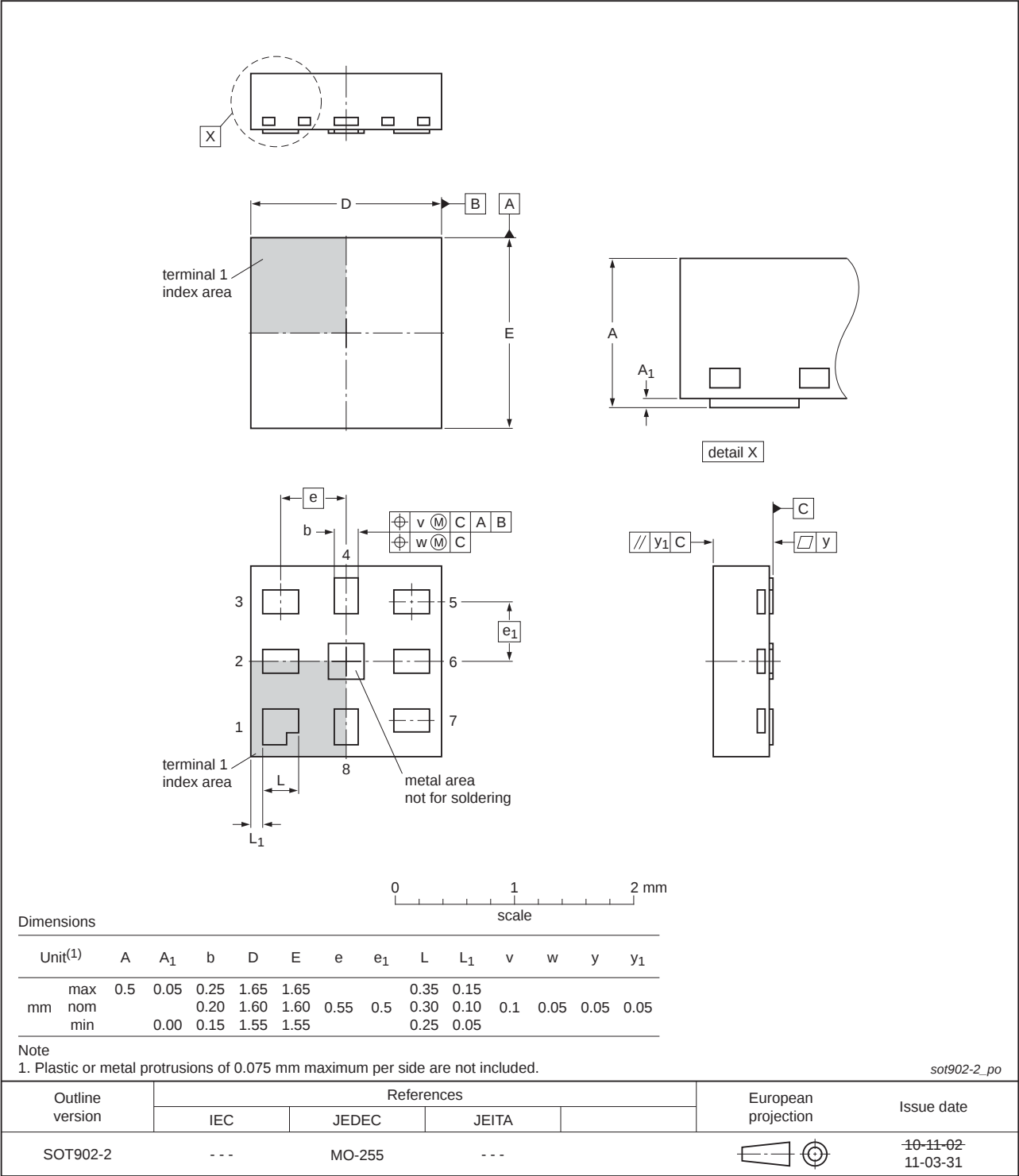


Fig 19. Package outline SOT902-2 (XQFN8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.2 x 1.0 x 0.35 mm

SOT1116

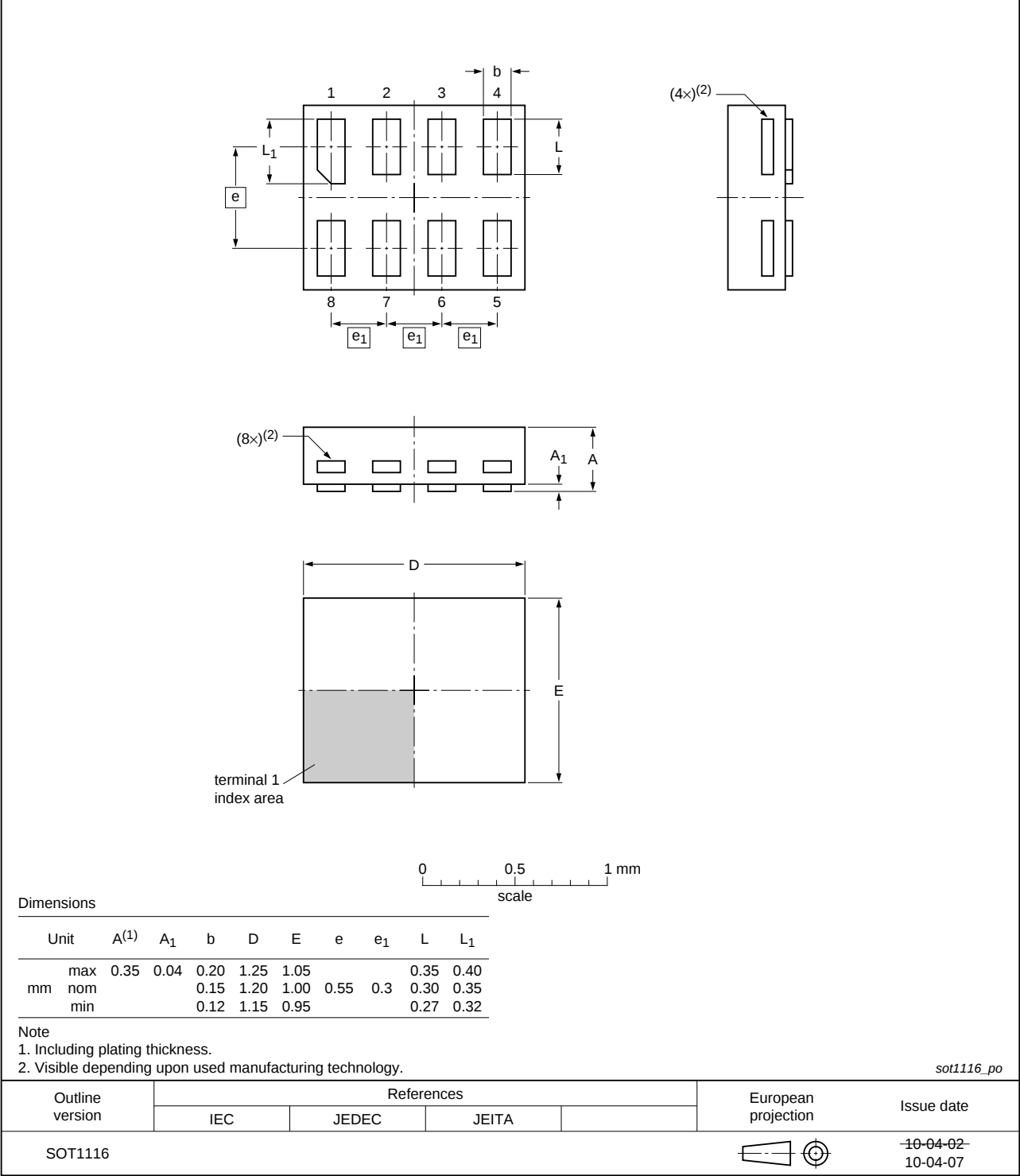


Fig 20. Package outline SOT1116 (XSON8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1.0 x 0.35 mm

SOT1203

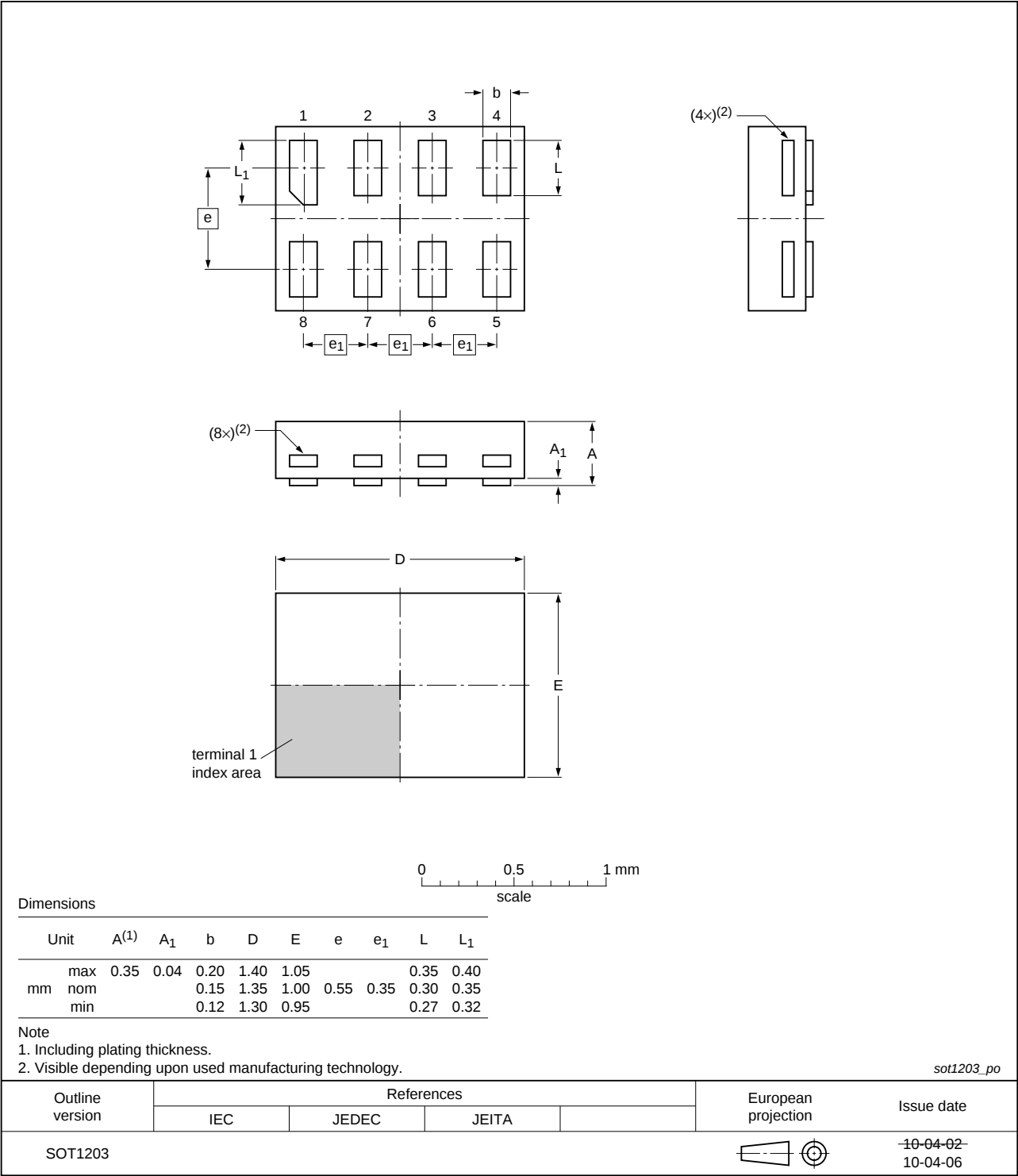


Fig 21. Package outline SOT1203 (XSON8)

## 18. Abbreviations

Table 12. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| HBM     | Human Body Model        |
| MM      | Machine Model           |

## 19. Revision history

Table 13. Revision history

| Document ID    | Release date                                                | Data sheet status  | Change notice | Supersedes     |
|----------------|-------------------------------------------------------------|--------------------|---------------|----------------|
| 74AUP2G132 v.7 | 20130208                                                    | Product data sheet | -             | 74AUP2G132 v.6 |
| Modifications: | • For type number 74AUP2G132GD XSON8U has changed to XSON8. |                    |               |                |
| 74AUP2G132 v.6 | 20120803                                                    | Product data sheet | -             | 74AUP2G132 v.5 |
| 74AUP2G132 v.5 | 20111201                                                    | Product data sheet | -             | 74AUP2G132 v.4 |
| 74AUP2G132 v.4 | 20101104                                                    | Product data sheet | -             | 74AUP2G132 v.3 |
| 74AUP2G132 v.3 | 20081215                                                    | Product data sheet | -             | 74AUP2G132 v.2 |
| 74AUP2G132 v.2 | 20080314                                                    | Product data sheet | -             | 74AUP2G132 v.1 |
| 74AUP2G132 v.1 | 20061018                                                    | Product data sheet | -             | -              |

## 20. Legal information

### 20.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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